SLVSAC2D - AUGUST 2010 - REVISED AUGUST 2012

# 2, 4-CHANNEL PROTECTION SOLUTION FOR SUPER-SPEED (6 GBPS) USB 3.0 INTERFACE

Check for Samples: TPD2EUSB30, TPD2EUSB30A, TPD4EUSB30

#### **FEATURES**

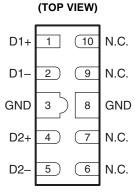
- Single and Dual-Pair Differential Lines to Protect the Differential Data and Clock Lines of the USB3.0, eSATA, or LVD Interface
- Flow-Through Pin Mapping for the High-Speed Lines Ensures near Zero Additional Skew Due to Board Layout While Placing Protection Chip Near the Connector
- Supports Data Rates in Excess of 6 Gbps
- ESD Protection Meets or Exceeds IEC61000-4-2 (Level 4)
- Low Capacitance 0.05pF (IO to IO)
- 0.6 Ω Dynamic Resistance
- 5-A Peak Pulse Current (per 8/20 μs Pulse)
- Industrial Temperature Range: -40°C to 85°C
- Space-Saving DRT, DQA Packages

# **APPLICATIONS**

- Notebooks
- Set-Top Boxes
- DVD Players
- Media Players
- Portable Computers

# DRT PACKAGE (TOP VIEW) D+ 1 3 GND

**DQA PACKAGE** 



# **DESCRIPTION/ORDERING INFORMATION**

The TPD2EUSB30, TPD2EUSB30A, and TPD4EUSB30 provide 2 and 4 channel ESD and surge protection solutions in space saving, flow-through packages. These devices have been designed to protect sensitive components which are connected to ultra high-speed data and transmission lines. These devices also offer 5 A (8/20 µs) peak pulse current ratings per IEC 61000-4-5 (lightning) specification.

The monolithic silicon technology allows matching between the differential signal pairs. The differential 0.05-pF capacitance ensures that the signal distortion due to added ESD clamp remains minimal at high-speed differential data transmission.

The TPD2EUSB30A offers low 4.5V dc break-down voltage. The low capacitance and break-down voltage, coupled low dynamic resistance, make the TPD2EUSB30A a superior ESD/ surge protection device for high-speed differential IOs based off ultra-low voltage process nodes.

The TPD2EUSB30 and TPD2EUSB30A are offered in space saving DRT (1 mm  $\times$  1 mm) package. The TPD4EUSB30 is offered in space saving DQA (1 mm  $\times$  2.5 mm) package. These devices are characterized for operation over ambient air temperature range of  $-40^{\circ}$ C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### ORDERING INFORMATION

T <sub>A</sub>	PACK	AGE <sup>(1) (2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING (3)
	SOT - DRT	Tape and reel	TPD2EUSB30DRTR	5P
-40°C to 85°C	SOT - DRT	Tape and reel	TPD2EUSB30ADRTR	5S
	SON - DQA	Tape and reel	TPD4EUSB30DQAR	66_

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (3) DQA: The actual top-side marking has one additional character that designates wafer fab/assembly site.

# **CIRCUIT DIAGRAMS**

Figure 1. TPD4EUSB30 Circuit

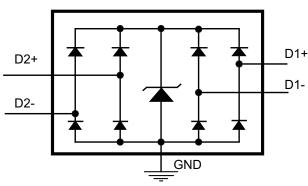
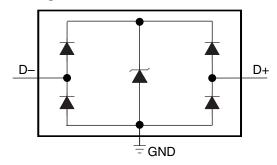


Figure 2. TPD2EUSB30/A Circuit



# **TERMINAL FUNCTIONS**

TERMINAL		L		
NAME	NAME DRT DQA PIN		TYPE	DESCRIPTION
Dx+, Dx–	1, 2	1,2, 4, 5	ESD port	High-speed ESD clamp, provides ESD protection to the high-speed differential data lines
GND	3	3, 8	GND	Ground
N.C.		6, 7, 9, 10		Not normally connected

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# ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
	IO voltage tolerance		D+, D- pins	0	6	
T <sub>A</sub>	Operating free-air tem	perature range	•	-40	85	°C
T <sub>stg</sub>	Storage temperature r	ange		-65	125	°C
	ESD protection	IEC 61000-4-2 Contact Discharge	D+, D- pins		±8	kV
		D protection IEC 61000-4-2 Air-Gap Discharge (TPD2EUSB30/A)			±8	kV
		IEC 61000-4-2 Air-Gap Discharge (TPD4EUSB30)	D+, D- pins		±9	kV
	Peak pulse current (tp	= 8/20 µs)	D+, D- pins		5	Α
	Peak pulse power (t <sub>p</sub> =	= 8/20 µs)	D+, D- pins		45	W

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

# **ELECTRICAL CHARACTERISTICS**

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	MIN	TYP	MAX	UNIT	
V	Reverse stand-off voltage, TPD2EUSB30, TPD4EUSB30	D+,D- pins to ground				5.5	V
V <sub>RWM</sub>	Reverse stand-off voltage, TPD2EUSB30A	D+,D- pins to ground			3.6	V	
$V_{clamp}$	Clamp voltage	D+,D- pins to ground,			8	V	
I <sub>IO</sub>	Current from IO port to supply pins	$V_{1O} = 2.5 V,$	$I_D = 8 \text{ mA}$		0.01	0.1	μΑ
V <sub>D</sub>	Diode forward voltage	D+,D- pins, lower clamp diode,	$V_{IO} = 2.5 \text{ V},$ $I_{D} = 8 \text{ mA}$	0.6	0.8	0.95	V
R <sub>dyn</sub>	Dynamic resistance	D+,D- pins	I = 1 A		0.6		Ω
$C_{\text{IO-IO}}$	Capacitance IO to IO	D+,D- pins	$V_{10} = 2.5 \text{ V}$		0.05		pF
		D+,D- pins (DRT)			0.7		
C <sub>IO-GND</sub>	Capacitance IO to GND	D1+, D1-, D2+, D2- (DQA )	V <sub>IO</sub> = 2.5 V		0.8		pF
V	Break-down voltage, TPD2EUSB30, TPD4EUSB30	I <sub>IO</sub> = 1 mA		7			V
$V_{BR}$	Break-down voltage, TPD2EUSB30A	I <sub>IO</sub> = 1 mA	4.5			V	



# TYPICAL OPERATING CHARACTERISTICS

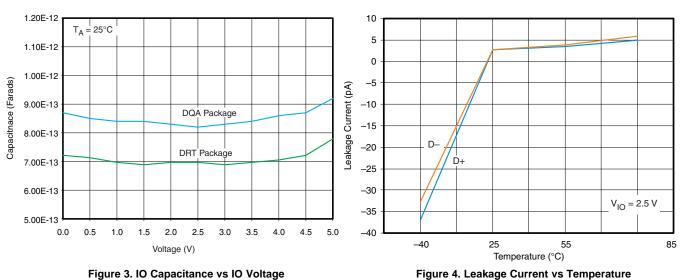
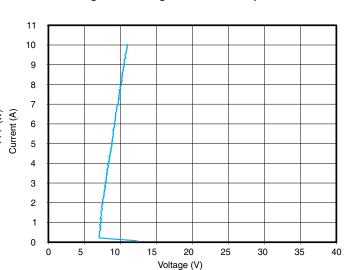


Figure 3. IO Capacitance vs IO Voltage



6.0 Measured at one IO, 5.5 55 the other IO open 5.0 50 4.5 45 40 4.0 PPP (W) Current (A) 3.5 35 IPP (A) 30 3.0 2.5 25 Current (A) 20 2.0 15 1.5 1.0 10 Power (W) 0.5 5 0 0.0 5 10 15 20 25 30 45 50 Time (µs)

Figure 5. Peak Pulse Waveforms

Figure 6. D+,D- Transmission Line Pulser Plot for TPD2EUSB30 (100 ns Pulse, 10 ns Rise Time)

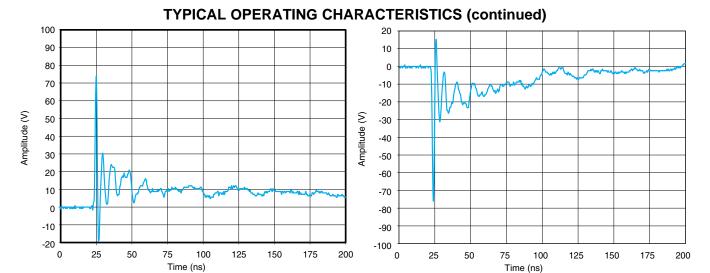


Figure 7. IEC Clamping Waveforms (8 kV Contact)

Figure 8. IEC Clamping Waveforms (-8 kV Contact)

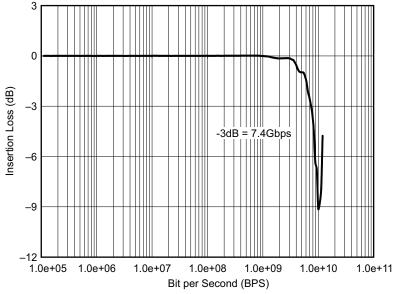


Figure 9. Insertion Loss



#### APPLICATION INFORMATION

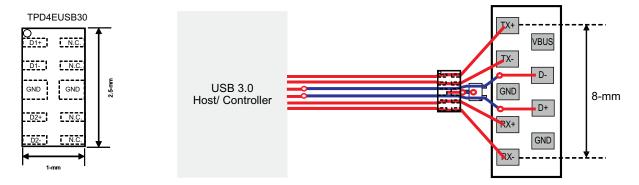
# Layout Guide with TPDxEUSB30/A

Refer to Figure 10, the TPD2EUSB30/A are offered in space saving DRT package. The DRT is a 1mm\* 1mm package with flow-through pin-mapping for the high-speed differential lines. The TPD4EUSB30 is offered in space saving DQA package. The DQA is a 1mm\* 2.5mm package with flow-through pin-mapping for the high-speed differential lines. It is recommended to place the package right next to the USB 3.0 connector. The GND pin should connected to GND plane of the board through a large VIA. If a dedicated GND plane is not present right underneath, it is recommended to route to the GND plane through a wide trace. The current associated with IEC ESD stress can be in the range of 30Amps or higher momentarily. A good, low impedance GND path ensures the system robustness against IEC ESD stress.

The TPDxEUSB30/A can provide system level ESD protection to the high-speed differential ports (>6 Gbps data rate). The flow-through package offers flexibility for board routing with traces up to 15 mills wide. It allows the differential signal pairs couple together right after they touch the ESD ports of the TPDxEUSB30/A.



Three TPD2EUSB30 to Protect USB3.0 Class A connector (One Layer Routing)



One TPD4EUSB30 & One TPD2EUSB30 to Protect USB3.0 Class A connector (Two Layer Routing)

Figure 10. Layout Guide with the TPDxEUSB30/A at the USB3.0 Class A Connector

# **TPDxEUSB30/A Eye Pattern Test**

See Figure 12 for a demonstration of the TPDxEUSB30/A performance the lab set-up. Figure 11 shows a lab board that was designed to demonstrate the degradation of the eye pattern quality with and without the TPD2EUSB30/A in the USB 3.0 signal path. Figure 13 shows that there is only ~2 ps jitter penalty to the differential signal when the TPD2EUSB30/A device was added in the signal path. Similar setup was employed to measure eye pattern for the TPD4EUSB30.

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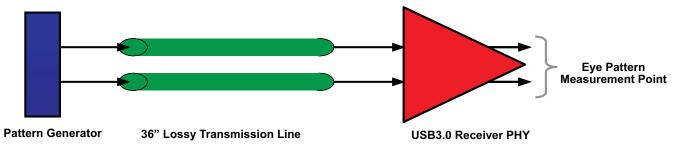


Figure 11. Measurement Setup to collect the Eye Pattern on a Reference Board with TPD2EUSB30/A

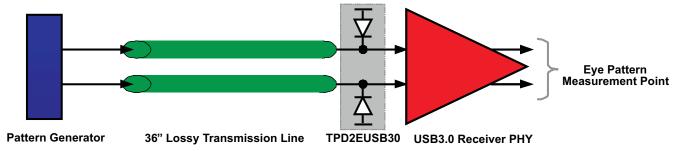


Figure 12. Measurement Setup to collect the Eye Pattern on a Reference Board with TPD2EUSB30/A

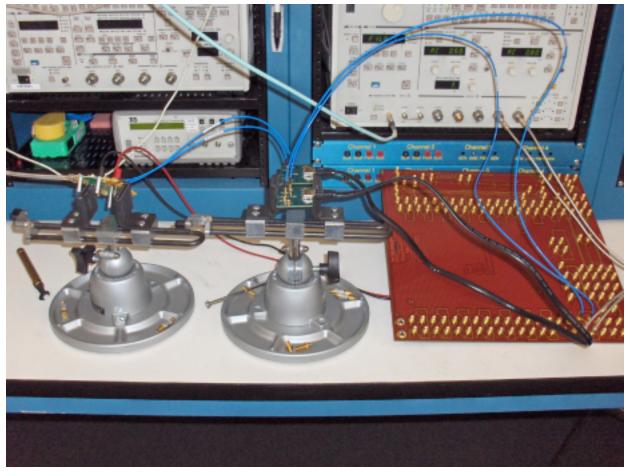


Figure 13. Lab Setup for the Eye-Pattern Measurement with TPDxEUSB30/A



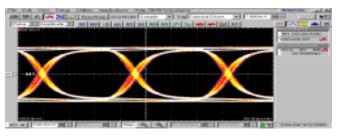


Figure 14. Output Eye Diagram Without TPD2EUSB30/A (Figure 11 Setup, 5 Gbps Data Rate)

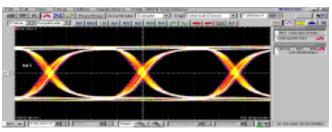


Figure 15. Output Eye Diagram with the TPD2EUSB30/A (Figure 11 Setup, 5 Gbps Data Rate)

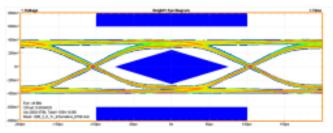


Figure 16. Output Eye Diagram Without the TPD4EUSB30 (5 Gbps Data Rate)

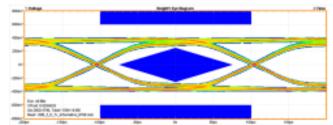


Figure 17. Output Eye Diagram with the TPD4EUSB30 (5 Gbps Data Rate)

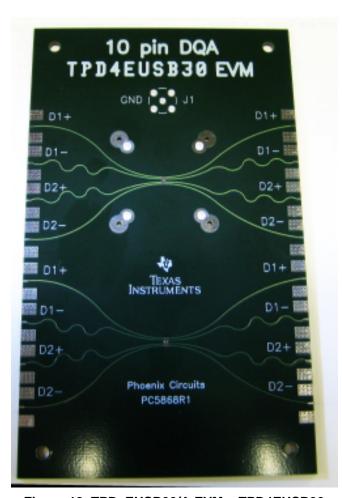


Figure 18. TPDxEUSB30/A EVM – TPD4EUSB30 Side

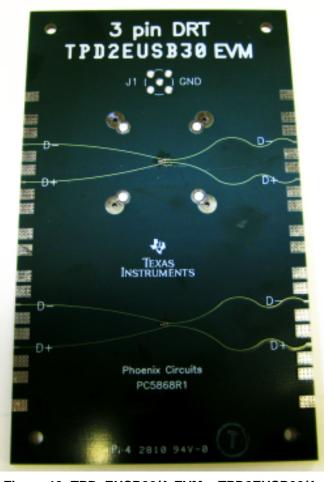


Figure 19. TPDxEUSB30/A EVM – TPD2EUSB30/A Side



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# **REVISION HISTORY**

Changes from Original (August 2010) to Revision A	Page
Added TPS2EUSB30A part to document.	1
Changes from Revision A (December 2010) to Revision B	Page
Changed TOP-SIDE MARKING column in the Ordering Information Table	2
Changes from Revision B (July 2011) to Revision C	Page
Added Insertion Loss graphic to TYPICAL OPERATING CHARACTERISTICS section	Ę
Changes from Revision December 2011 (C) to Revision D	Page
Updated Dynamic Resistance value.	1
Updated Dynamic Resistance value	3



# PACKAGE OPTION ADDENDUM

26-Mar-2013

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
TPD2EUSB30ADRTR	ACTIVE	SOT	DRT	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	5S	Samples
TPD2EUSB30DRTR	ACTIVE	SOT	DRT	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	5P	Samples
TPD4EUSB30DQAR	ACTIVE	SON	DQA	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(667 ~ 66O ~ 66R)	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

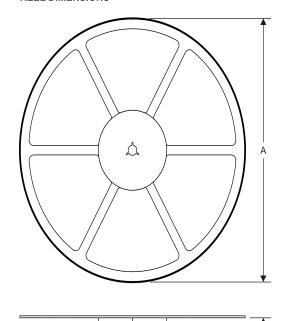
<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

# PACKAGE MATERIALS INFORMATION

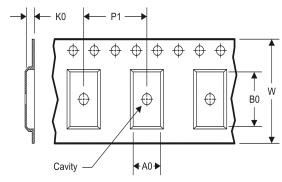
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# TAPE AND REEL INFORMATION

# **REEL DIMENSIONS**







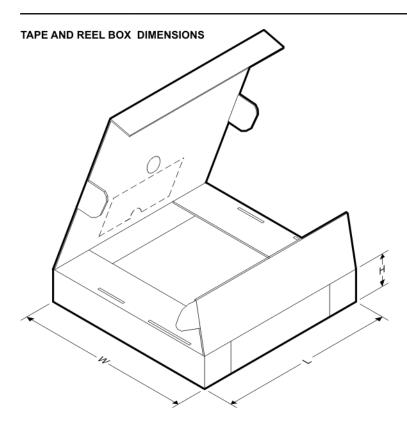
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

# TAPE AND REEL INFORMATION

\*All dimensions are nominal

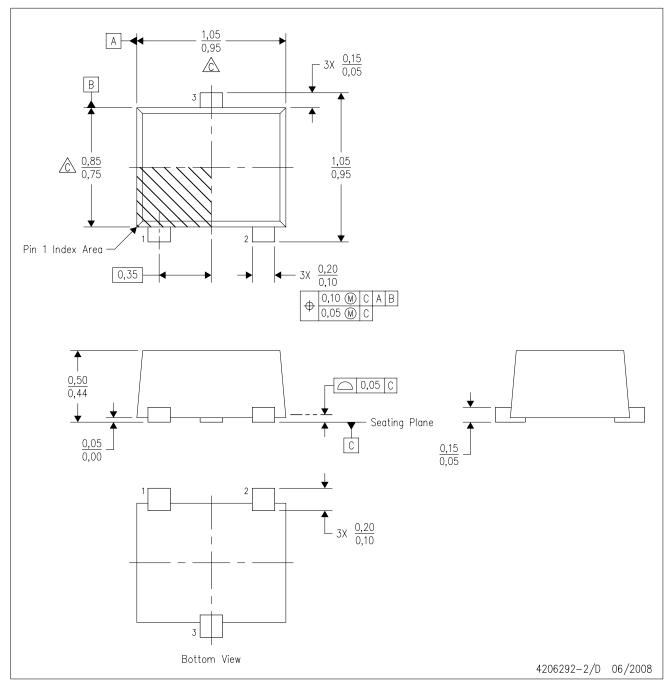
All differsions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPD2EUSB30ADRTR	SOT	DRT	3	3000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q3
TPD2EUSB30DRTR	SOT	DRT	3	3000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q3
TPD4EUSB30DQAR	SON	DQA	10	3000	180.0	8.4	1.3	2.83	0.65	4.0	8.0	Q1
TPD4EUSB30DQAR	SON	DQA	10	3000	179.0	8.4	1.25	2.8	0.7	4.0	8.0	Q1

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\*All dimensions are nominal

7 III GITTIOTOTOTO GITO TTOTTIITIGI							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPD2EUSB30ADRTR	SOT	DRT	3	3000	202.0	201.0	28.0
TPD2EUSB30DRTR	SOT	DRT	3	3000	202.0	201.0	28.0
TPD4EUSB30DQAR	SON	DQA	10	3000	202.0	201.0	28.0
TPD4EUSB30DQAR	SON	DQA	10	3000	203.0	203.0	35.0



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

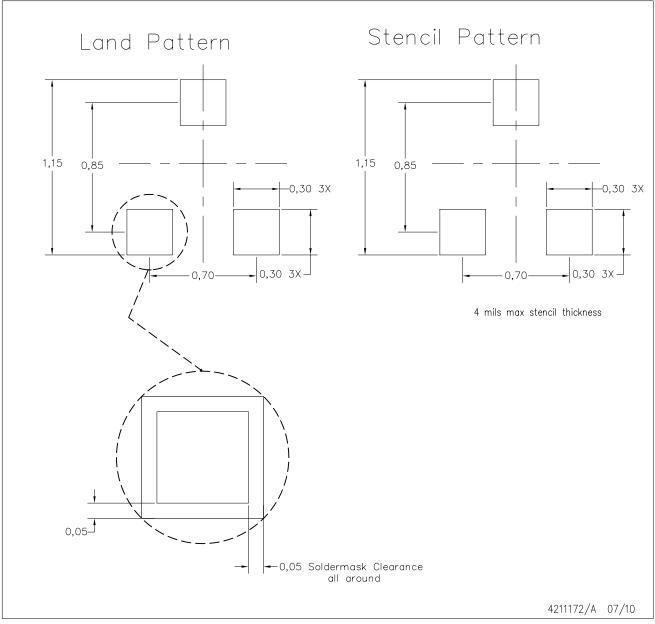
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

  Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,10 per end or side.
- D. JEDEC package registration is pending.



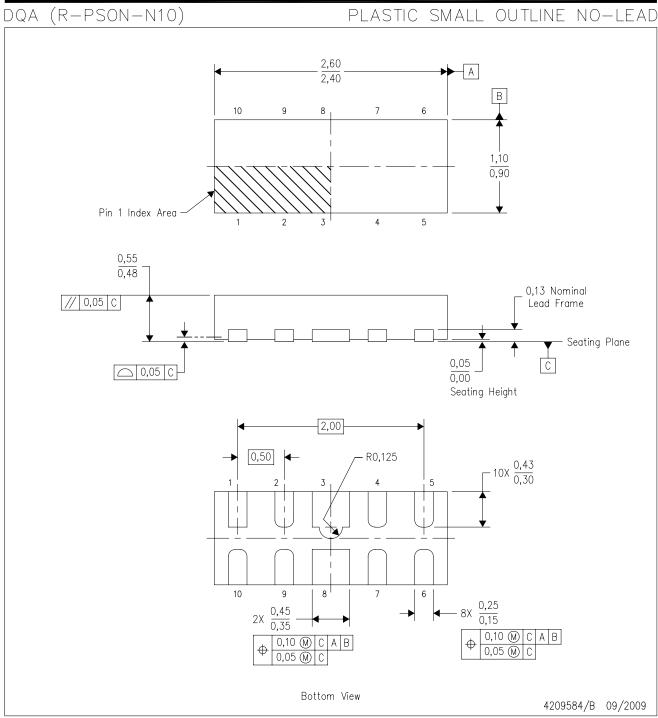
# DRT (S-PDSO-N3)

# PLASTIC SMALL OUTLINE



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
  - E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
  - F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.





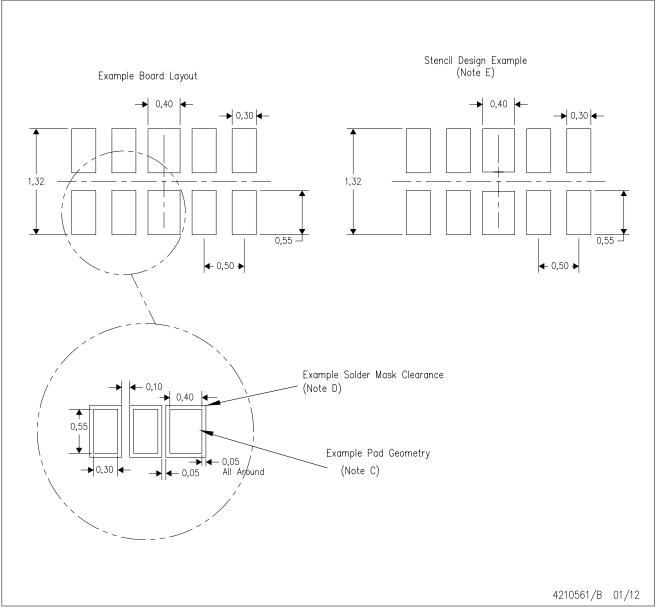
NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.C. SON (Small Outline No-Lead) package configuration.



# DQA (R-PUSON-N10)

# PLASTIC SMALL OUTLINE NO-LEAD



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
  - E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
  - F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



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In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

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Microcontrollers <u>microcontroller.ti.com</u> Video and Imaging <u>www.ti.com/video</u>

RFID www.ti-rfid.com

OMAP Applications Processors <a href="www.ti.com/omap">www.ti.com/omap</a> TI E2E Community <a href="e2e.ti.com">e2e.ti.com</a>

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

# Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов:
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001:
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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